

Supporting information

Nickel-Doped VS₄ Nanostructures as a Promising Candidate for Nonlinear Optical Limiter

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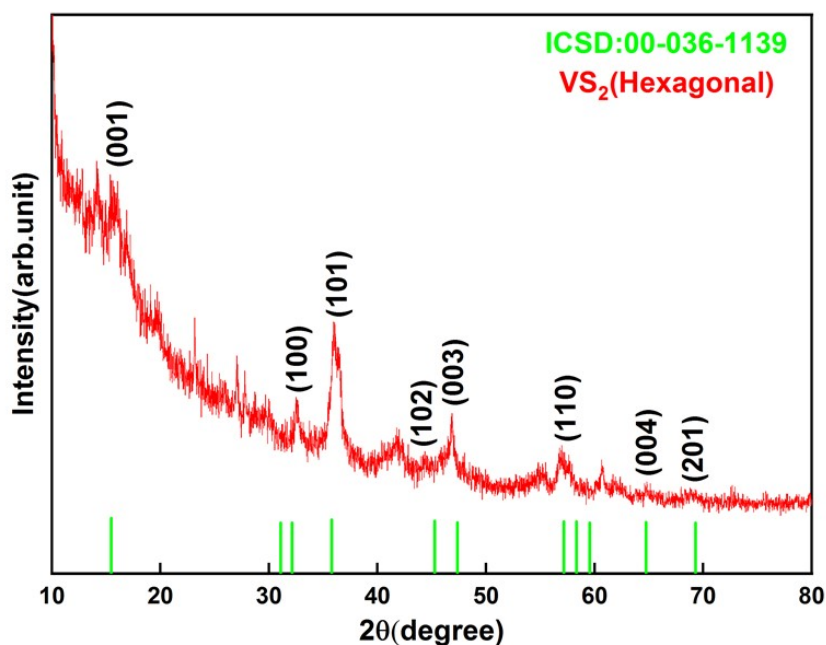


Figure S1: XRD pattern of VS₂.

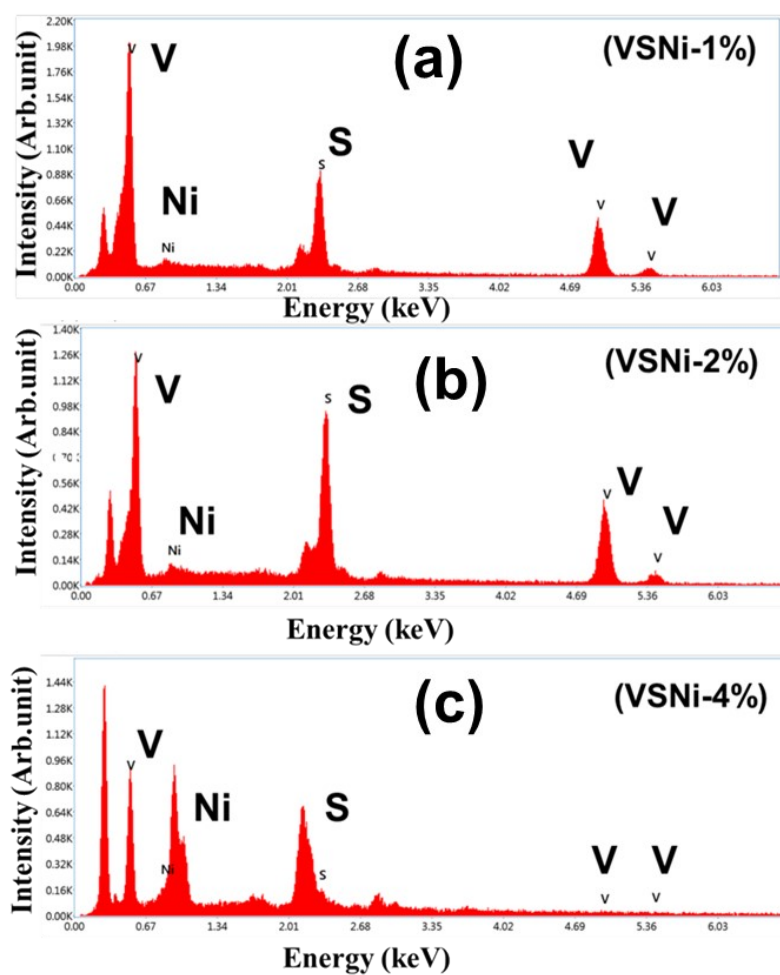


Figure S2. EDX spectra of (a) VSNi-1%, (b) VSNi-2% and, (c) VSNi-4%.

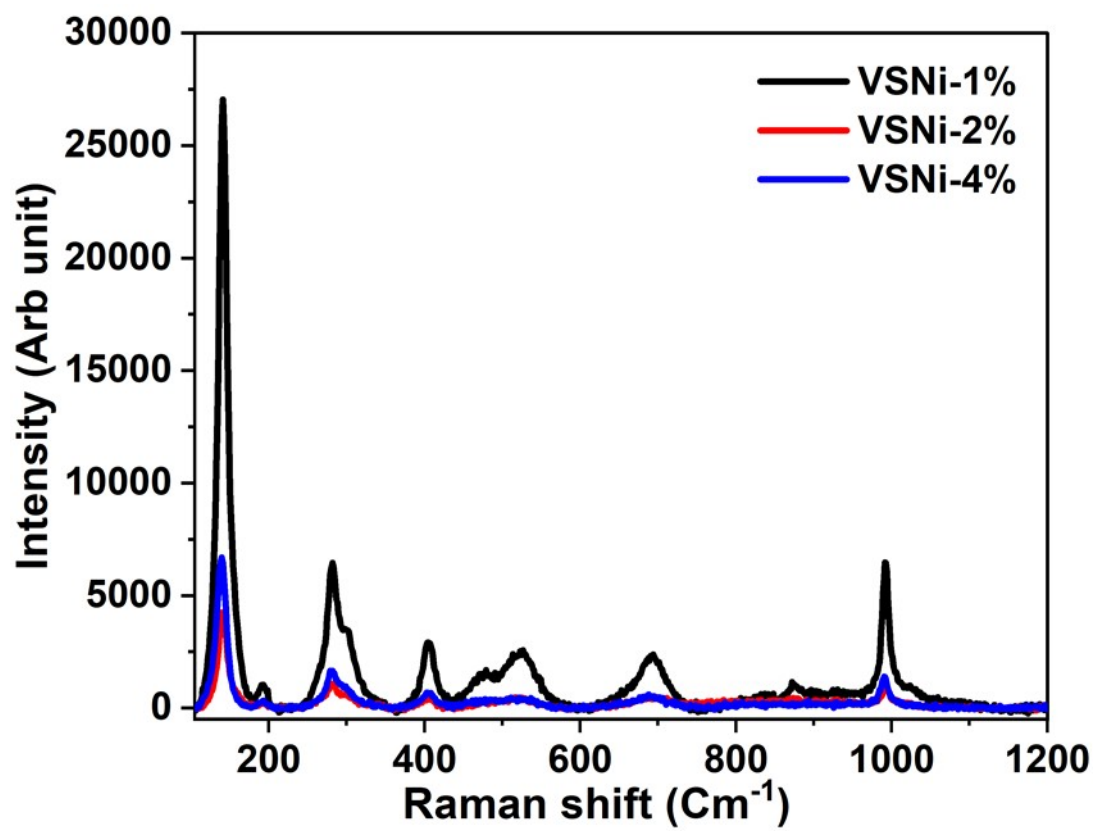


Figure S3 Raman spectra (Peak broadening)

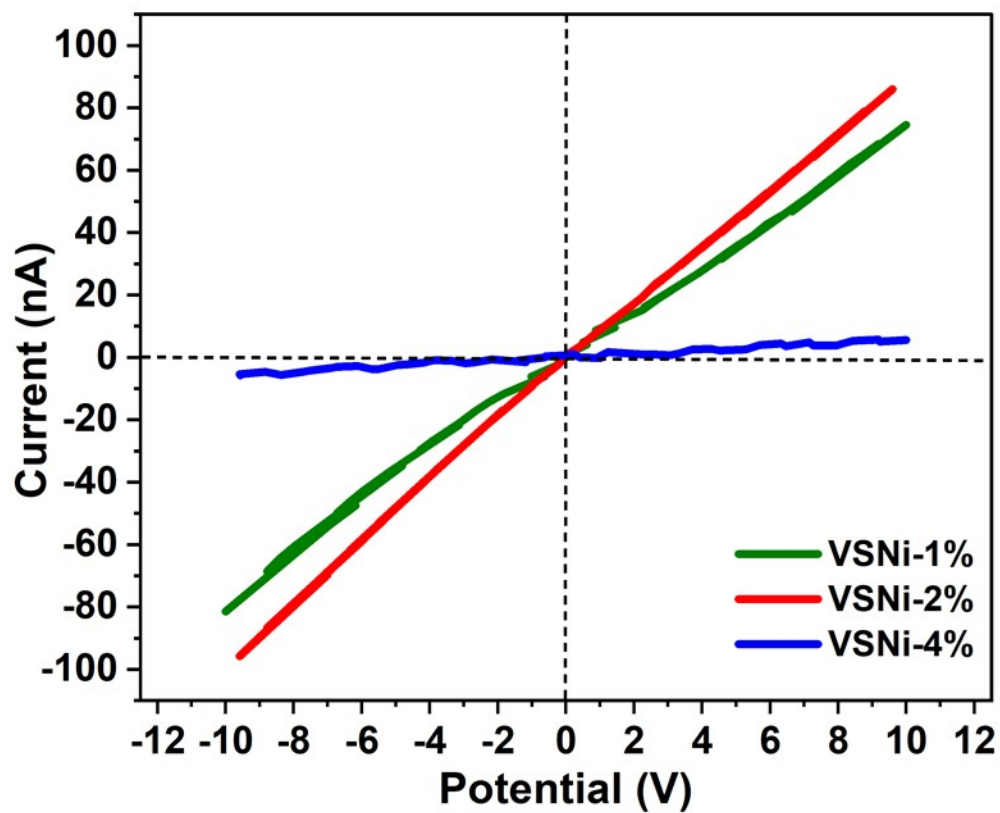


Figure S4 IV plot of VSNi-1%, VSNi-2% and VSNi-4% sample.

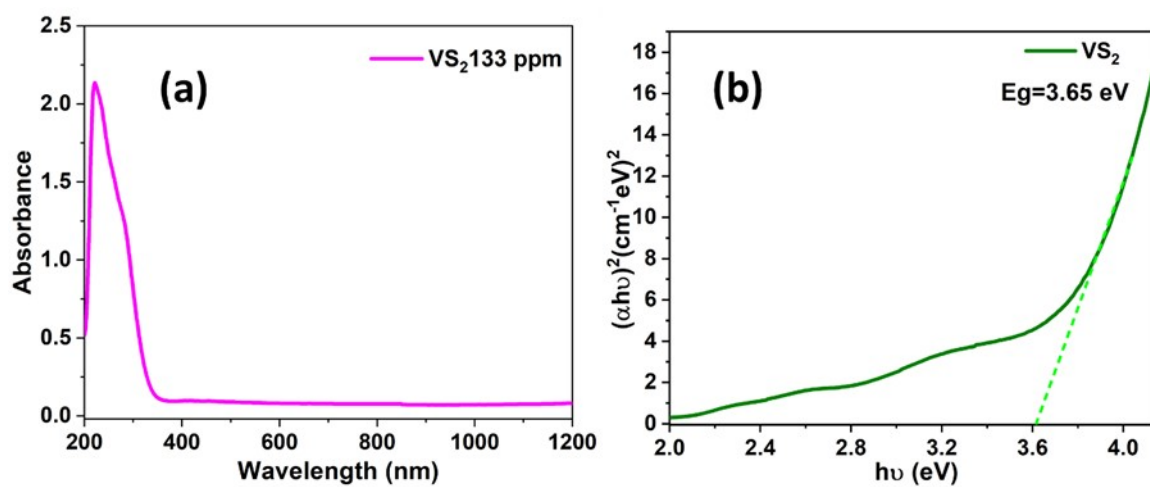


Figure S5 (a) Absorbance plot, (b) Tauc plot.

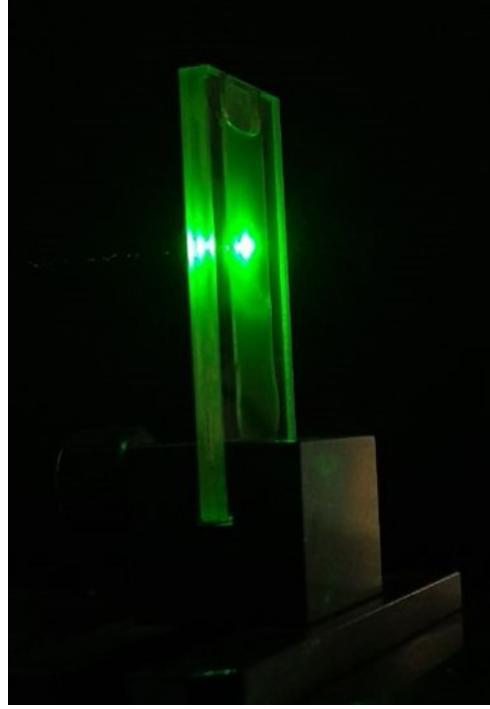


Figure S6 (Sample taken in 1mm cuvette)

Table S1 (Nonlinear comparison table for previously reported journal)

Sample name	Synthesis method	Laser source	β (cm/GW)	n_2 cm ² /GW	Ref.
VS ₂	hydrothermal	nanosecond laser pulses at 532 nm wavelength	0 29 17 27		[1] SA
VS ₂ BP VS ₂ /BP Nano hybrid	hydrothermal	120 fs, 800 nm excitation.	$-(2.0 \pm 0.4) \times 10^{-3}$ $-(8.0 \pm 0.6) \times 10^{-3}$ $(165 \pm 20) \times 10^{-3}$	$(4 \pm 0.5) \times 10^{-6}$ $(6.0 \pm 0.7) \times 10^{-6}$ $(120 \pm 10) \times 10^{-6}$	[2] ESA
VS ₂ Rgo VS ₂ /rGO	Hydrothermal	532 nm 5 ns pulses	$-(4 \pm 1)$ (12 ± 2) (122 ± 4)	$(3 \pm 0.2) \times 10^{-5}$ $(4 \pm 0.3) \times 10^{-5}$ $(48.0 \pm 2) \times 10^{-5}$	[3] Weak TPA ESA
VS ₂ /Ti ₃ C ₂ MXene	hydrothermal excited state absorption (ESA)	800 nm 120 fs pulses	$(8.0 \pm 0.2) \times 10^2$	$(4.2 \pm 0.2) \times 10^{-6}$	[4] ESA

VS ₂ -NiS ₂	Hydrothermal l (TPA)	532-CW laser Nd:YAG laser	(0.141–2.025) *10 ⁻³ (cm/w)	24.23–35.62	[5] TPA
MoS ₂	SA-TPA CVD	532	(31.18-145.72) cm/W	(3.11-5.16) × 10 ⁻⁴ (cm ² /W)	[6] SA TPA
VS₂ VMS-1 VMS-2 VMS-3	Hydrothermal l SA- 2PA(RSA)	532 DPSS CW laser (100 mW)	cm/W -(24.15 ± 0.25) 0.183±127E-4 0.115±3.96E-4 0.139±3.084E-5	× 10 ⁴ 1.168±0.023 0.023±0.013 0.181±0.072 1.758±0.295	[7] SA RSA
VSCo-1% VSCo-2% VSCo-4%	Hydrothermal l 2PA(RSA) Self defocusing	532 DPSS CW laser (100 mW)	Cm/W × 10 ⁻² 2.163 ± 0.009 1.911 ± 0.081 0.851 ± 0.002	-(cm ² /GW) × 10 ² 0.673±0.041 1.053±0.018 1.50299± 0.024	[8] RSA/2P A
VSNi-1% VSNi-2% VSNi-4%	Hydrothermal l (RSA, Self- defocusing)	532 DPSS CW laser (100 mW)	2.118 ± 0.107 1.9174 ± 0.078 1.8073 ± 0.079	7.154±0.651 7.173±0.786 4.788± 0.383	This work RSA

Reference

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Table S2 (Band gap comparison from the literature)

Morphology /method	Reported band gap	Reference
Thin films of VS ₄ for energy conversion.	Direct optical gap (1.35 ± 0.05 eV)	[1]
VS ₄ nanorods/heterostructure for microwave absorption	1.0 eV	[2]
VS ₄ nanoplates in composite(Ag ₂ WO ₄ /VS ₄)photocatalysis	DFT 1.2 eV	[3]
VS ₄ /graphitic-C ₃ N ₄ nanocomposite produced byhydrothermal	2.74 eV for composite	[4]

Reference:

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